



2.0A SURFACE MOUNT ULTRA-FAST RECTIFIER

Product Summary (@TA = +25°C)

V _{RRM} (V)	I _O (A)	V _F (MAX) (V)	I _{R(MAX)} (μA)
600	2	1.7	5

Description and Applications

The US2JDFQ is a rectifier packaged in the low profile D-FLAT package. Providing ultra-fast recovery time for high efficiency, this device is ideal for use in applications such as:

- Reverse Protection
- Switching
- Blocking

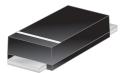
Features and Benefits

- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 50A Peak
- High Current Capability
- Low Profile Design, Package Height less than 1.1mm
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standard for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: D-FLAT
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 @3
- · Polarity: Cathode Band
- Weight: 0.036 grams (Approximate)

D-FLAT



Top View

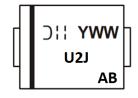
Ordering Information (Note 5)

Ī	Part Number	Qualification	Case	Packaging
	US2JDFQ-13	Automotive	D-FLAT	10,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 6)	V _{RRM} V _{RWM} V _R	600	>
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectified Output Current @ $T_T = +75$ °C	I _O	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		50	Α

Thermal Characteristics

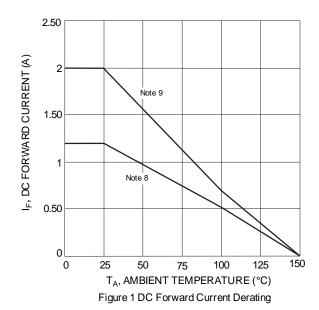
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal	$R_{\theta JT}$	22	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

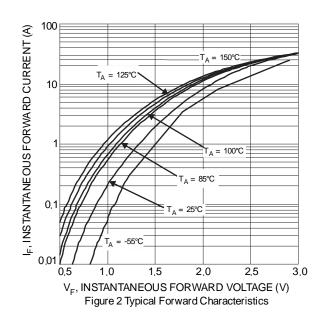
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Minimum Reverse Breakdown Voltage (Note 6)	$@I_R = 5\mu A$	$V_{(BR)R}$	600	V
Maximum Forward Voltage Drop			1.7	V
$@ I_F = 1.0A$		V_{F}	1.7	V
Peak Reverse Current	@ T _A = +25°C		5.0	
at Rated DC Blocking Voltage (Note 6)	@ $T_A = +100$ °C	IR	100	μΑ
Maximum Reverse Recovery Time (Note 7)		t _{RR}	75	ns
Typical Total Capacitance (Note 10)		Ст	10	pF

Notes:

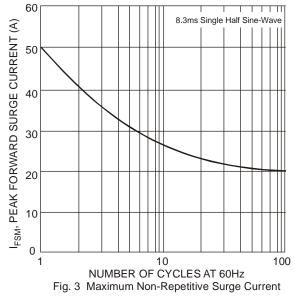
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See Figure 7.
- 8. Device mounted on FR-4 substrate, 1inch × 1inch, 2oz, single-sided, PC boards with 0.1inch × 0.15inch copper pads.
- 9. Device mounted on FR-4 substrate, 0.4inch × 0.5inch, 2oz, single-sided, PC boards with 0.2inch × 0.25inch copper pads.
- 10. Measured at f=1.0MHz and applied reverse voltage of 4.0V DC.

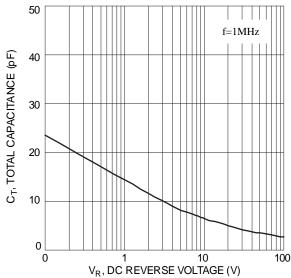


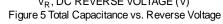












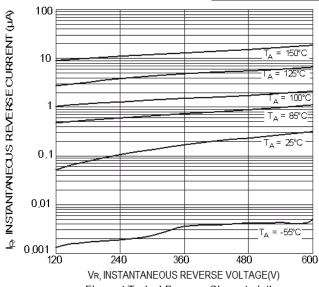


Figure 4 Typical Reverse Characteristics

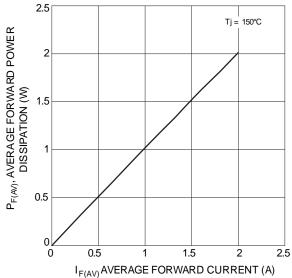
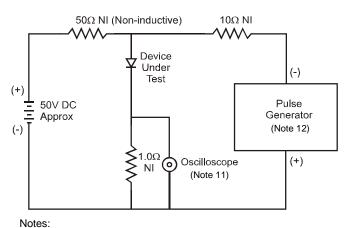
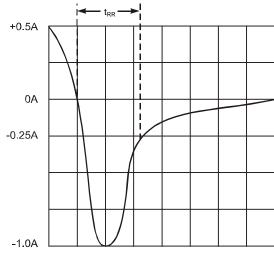


Figure 6 Forward Power Dissipation



11. Rise Time = 7.0ns max. Input Impedance = 1.0M Ω , 22pF. 12. Rise Time = 10ns max. Input Impedance = 50Ω .



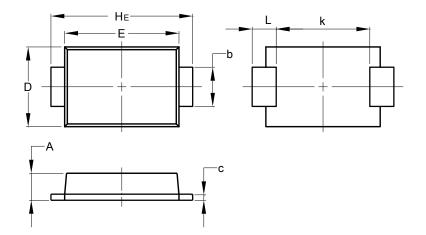
Set time base for 50/100 ns/cm

Fig. 7 Reverse Recovery Time Characteristic and Test Circuit



Package Outline Dimensions

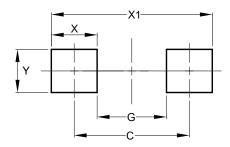
Please see http://www.diodes.com/package-outlines.html for the latest version.



D-FLAT				
Dim	Min	Max		
Α	0.90	1.10		
b	1.25	1.65		
C	0.10	0.40		
D	2.25	2.95		
Е	3.95	4.60		
k	2.80	-		
HE	5.00	5.60		
L	0.50	1.30		
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value	
	(in mm)	
С	4.65	
G	2.80	
X	1.85	
X1	6.50	
Y	1.70	



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

www.diodes.com